

NCE85H21T

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE85H21T uses advanced trench technology and design to provide excellent $R_{\text{DS(ON)}}$ with low gate charge. It can be used in automotive applications and a wide variety of other applications.

General Features

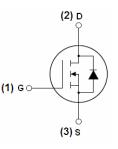
- V_{DSS} =85V, I_D =210A $R_{DS(ON)}$ < 3.5mΩ @ V_{GS} =10V
- Good stability and uniformity with high E_{AS}
- Special process technology for high ESD capability
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

Application

- Automotive applications
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

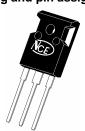
100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



TO-247 top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity	
NCE85H21T	NCE85H21T	TO-247	-	-	-	

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DSS}	85	V
Gate-Source Voltage	V _G S	±20	V
Drain Current-Continuous	I _D	210	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	150	Α
Pulsed Drain Current	I _{DM}	850	Α
Maximum Power Dissipation	P _D	330	W
Derating factor		2.2	W/°C
Single pulse avalanche energy (Note 3)	E _{AS}	2200	mJ
Peak Diode Recovery dv/dt (Note 4)	dv/dt	5	V/ns
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 175	$^{\circ}$



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NCE85H21T

Thermal Characteristic

Electrical Characteristics (T_C=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	<u>.</u>					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	85	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =85V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±200	nA
On Characteristics	·					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2	3	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =40A	-	2.9	3.5	mΩ
Forward Transconductance	G FS	V _{DS} =25V,I _D =40A	100	165	-	S
Dynamic Characteristics	<u>.</u>					
Input Capacitance	C _{lss}	\/ -05\/\/ -0\/	-	11000	-	PF
Output Capacitance	Coss	V_{DS} =25V, V_{GS} =0V, F=1.0MHz	-	914	-	PF
Reverse Transfer Capacitance	C _{rss}	r=1.0lvlm2	-	695	-	PF
Switching Characteristics	·					
Turn-on Delay Time	t _{d(on)}		-	23	-	nS
Turn-on Rise Time	t _r	V_{DD} =30V, I_D =2A, R_L =15 Ω	-	190	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =2.5 Ω	-	130	-	nS
Turn-Off Fall Time	t _f		-	120	-	nS
Total Gate Charge	Qg		-	250	-	nC
Gate-Source Charge	Q _{gs}	ID=30A,VDD=30V,VGS=10V	-	48	-	nC
Gate-Drain Charge	Q _{gd}		-	98	-	nC
Drain-Source Diode Characteristics	·					
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =40A	-	-	1.2	V
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 40A	-	63	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note2)	-	98	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

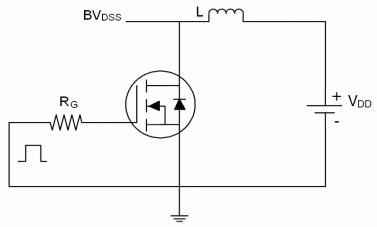
Notes:

- 1. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 2. Pulse Test: Pulse Width \leq 400 μ s, Duty Cycle \leq 2%.
- 3. EAS condition: Tj=25 $^{\circ}\text{C}$,VDD=42.5V,VG=10V,L=2mH,Rg=25 Ω ,IAS=37A
- 4. Isd \leqslant 125A, di/dt \leqslant 260A/ μ s, Vdd \leqslant V(BR)dss, TJ \leqslant 175°C

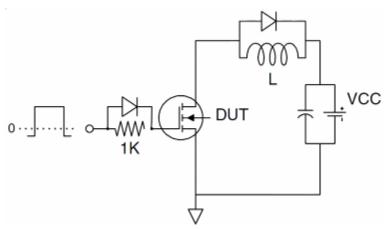


Test Circuit

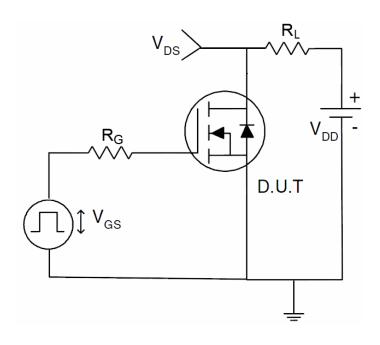
1) E_{AS} test Circuit



2) Gate charge test Circuit

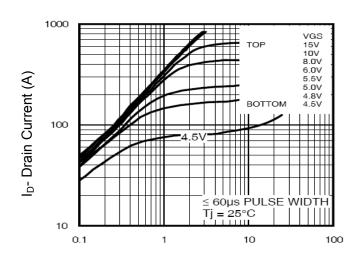


3) Switch Time Test Circuit



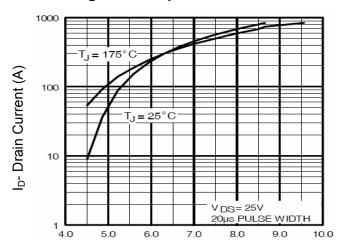


Typical Electrical and Thermal Characteristics



Vds Drain-Source Voltage (V)





Vgs Gate-Source Voltage (V)

Figure 2 Transfer Characteristics

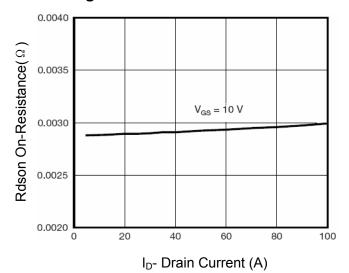
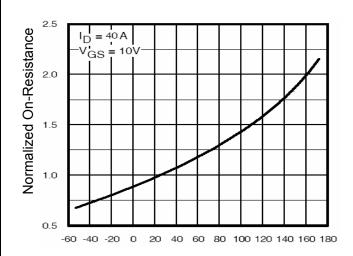


Figure 3 Rdson- Drain Current



 T_J -Junction Temperature($^{\circ}$ C)

Figure 4 Rdson-JunctionTemperature

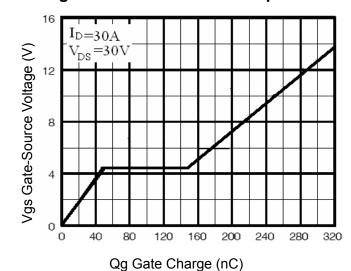


Figure 5 Gate Charge

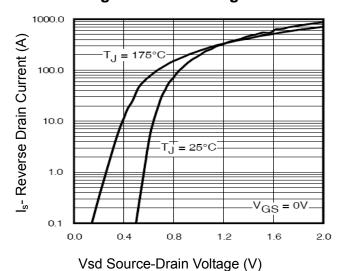


Figure 6 Source- Drain Diode Forward



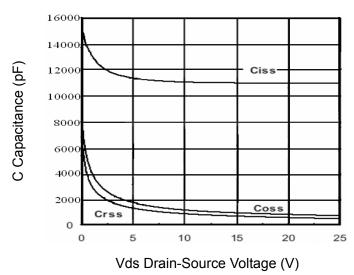


Figure 7 Capacitance vs Vds

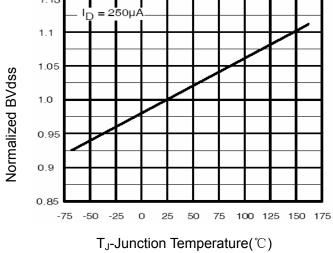


Figure 9 BV_{DSS} vs Junction Temperature

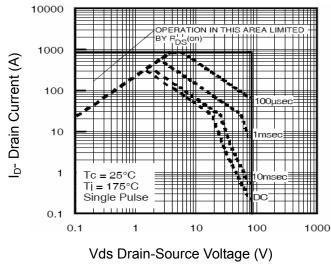
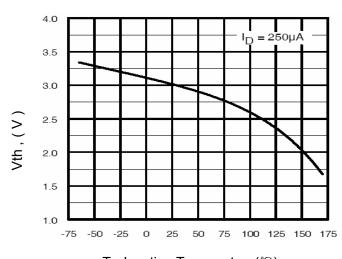
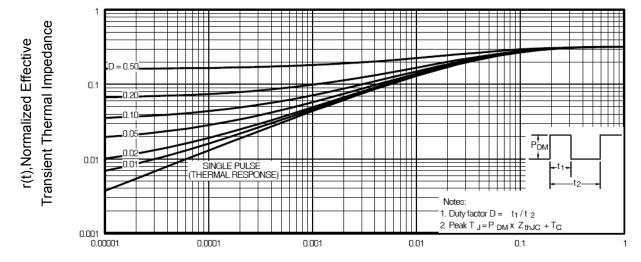


Figure 8 Safe Operation Area



 T_J -Junction Temperature($^{\circ}$ C)

Figure 10 V_{GS(th)} vs Junction Temperature



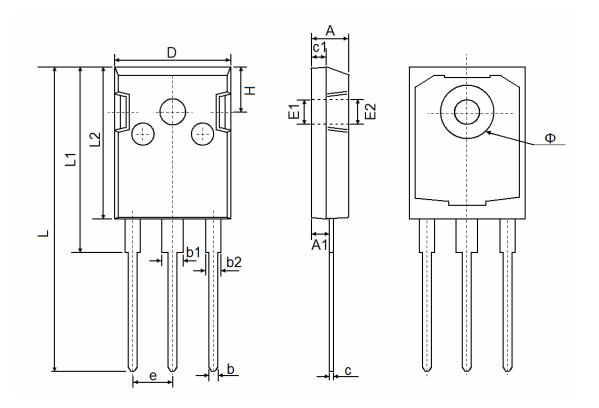
Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance

Pb Free Product

NCE85H21T

TO-247 Package Information



Complete	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min.	Max.	Min.	Max.		
А	4.850	5.150	0.191	0.200		
A1	2.200	2.600	0.087	0.102		
b	1.000	1.400	0.039	0.055		
b1	2.800	3.200	0.110	0.126		
b2	1.800	2.200	0.071	0.087		
С	0.500	0.700	0.020	0.028		
c1	1.900	2.100	0.075	0.083		
D	15.450	15.750	0.608	0.620		
E1	3.500	REF	0.138	REF		
E2	3.600	3.600 REF		0.142 REF		
L	40.900	41.300	1.610	1.626		
L1	24.800	25.100	0.976	0.988		
L2	20.300	20.600	0.799	0.811		
Ф	7.100	7.300	0.280	0.287		
е	5.450	5.450 TYP		0.215 TYP		
Н	5.980 REF		0.235 REF			



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